

N-Channel Enhancement-Mode Vertical DMOS FET

Features

- Low Threshold
- High Input Impedance
- Low Input Capacitance
- Fast Switching Speeds
- Low On-Resistance
- Free from Secondary Breakdown
- Low Input and Output Leakage

Applications

- Logic-Level Interfaces (Ideal for TTL and CMOS)
- Solid-State Relays
- Battery-Operated Systems
- Photovoltaic Drives
- Analog Switches
- General Purpose Line Drivers
- Telecommunication Switches

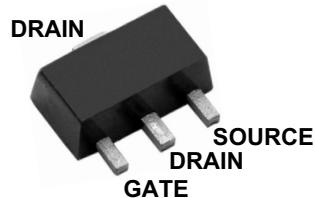
General Description

The TN2435 low-threshold Enhancement-mode (normally-off) transistor uses a vertical DMOS structure and a well-proven silicon-gate manufacturing process. This combination produces a device with the power handling capabilities of bipolar transistors and the high input impedance and positive temperature coefficient inherent in MOS devices. Characteristic of all MOS structures, this device is free from thermal runaway and thermally induced secondary breakdown.

Microchip's vertical DMOS FETs are ideally suited to a wide range of switching and amplifying applications where very low threshold voltage, high breakdown voltage, high input impedance, low input capacitance, and fast switching speeds are desired.

Package Type

**3-lead SOT-89
(Top view)**



See [Table 3-1](#) for pin information.

1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings†

| | |
|---|-------------------|
| Drain-to-Source Voltage | BV _{DSS} |
| Drain-to-Gate Voltage | BV _{DGS} |
| Gate-to-Source Voltage | ±20V |
| Operating Ambient Temperature, T _A | -55°C to +150°C |
| Storage Temperature, T _S | -55°C to +150°C |

† **Notice:** Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

Electrical Specifications: T_A = 25°C unless otherwise specified. All DC parameters are 100% tested at 25°C unless otherwise stated. (Pulse test: 300 µs pulse, 2% duty cycle)

| Parameter | Sym. | Min. | Typ. | Max. | Unit | Conditions |
|--|----------------------|------|------|------|-------|---|
| Drain-to-Source Breakdown Voltage | BV _{DSS} | 350 | — | — | V | V _{GS} = 0V, I _D = 250 µA |
| Gate Threshold Voltage | V _{GS(th)} | 0.8 | — | 2.5 | V | V _{GS} = V _{DS} , I _D = 1 mA |
| Change in V _{GS(th)} with Temperature | ΔV _{GS(th)} | — | — | -5.5 | mV/°C | V _{GS} = V _{DS} , I _D = 1 mA (Note 1) |
| Gate Body Leakage Current | I _{GSS} | — | — | 100 | nA | V _{GS} = ±20V, V _{DS} = 0V |
| Zero-Gate Voltage Drain Current | I _{DSS} | — | — | 10 | µA | V _{GS} = 0V, V _{DS} = Maximum rating (Note 1) |
| | | — | — | 1 | mA | V _{DS} = 0.8 Maximum rating, V _{GS} = 0V, T _A = 125°C |
| On-State Drain Current | I _{D(ON)} | 0.5 | — | — | A | V _{GS} = 4.5V, V _{DS} = 25V |
| | | 1 | — | — | A | V _{GS} = 10V, V _{DS} = 25V |
| Static Drain-to-Source On-State Resistance | R _{DS(ON)} | — | — | 15 | Ω | V _{GS} = 3V, I _D = 150 mA |
| | | — | — | 10 | Ω | V _{GS} = 4.5V, I _D = 250 mA |
| | | — | — | 6 | Ω | V _{GS} = 10V, I _D = 750 mA |
| Change in R _{DS(ON)} with Temperature | ΔR _{DS(ON)} | — | — | 1.7 | %/°C | V _{GS} = 10V, I _D = 750 mA (Note 1) |

Note 1: Specification is obtained by characterization and is not 100% tested.

AC ELECTRICAL CHARACTERISTICS

Electrical Specifications: $T_A = 25^\circ\text{C}$ unless otherwise specified. All AC parameters are not 100% sample tested.

| Parameter | Sym. | Min. | Typ. | Max. | Unit | Conditions |
|----------------------------------|--------------|------|------|------|------|--|
| Forward Transconductance | G_{FS} | 125 | — | — | mmho | $V_{DS} = 20\text{V}$, $I_D = 350\text{ mA}$ |
| Input Capacitance | C_{ISS} | — | 125 | 200 | pF | $V_{GS} = 0\text{V}$, $V_{DS} = 25\text{V}$, $f = 1\text{ MHz}$ |
| Common-Source Output Capacitance | C_{OSS} | — | 25 | 70 | pF | |
| Reverse Transfer Capacitance | C_{RSS} | — | 8 | 25 | pF | |
| Turn-On Delay Time | $t_{d(ON)}$ | — | 5 | 20 | ns | $V_{DD} = 25\text{V}$, $I_D = 750\text{ mA}$, $R_{GEN} = 25\Omega$ |
| Rise Time | t_r | — | 10 | 20 | ns | |
| Turn-Off Delay Time | $t_{d(OFF)}$ | — | 28 | 40 | ns | |
| Fall Time | t_f | — | 10 | 30 | ns | |
| DIODE PARAMETER | | | | | | |
| Diode Forward Voltage Drop | V_{SD} | — | — | 1.5 | V | $V_{GS} = 0\text{V}$, $I_{SD} = 750\text{ mA}$ (Note 1) |
| Reverse Recovery Time | t_{rr} | — | 300 | — | ns | $V_{GS} = 0\text{V}$, $I_{SD} = 750\text{ mA}$ |

Note 1: All DC parameters are 100% tested at 25°C unless otherwise stated.

(Pulse test: 300 μs pulse, 2% duty cycle)

TEMPERATURE SPECIFICATIONS

| Parameter | Sym. | Min. | Typ. | Max. | Unit | Conditions |
|-----------------------------------|---------------|------|------|------|--------------------|------------|
| TEMPERATURE RANGE | | | | | | |
| Operating Ambient Temperature | T_A | -55 | — | +150 | $^\circ\text{C}$ | |
| Storage Temperature | T_S | -55 | — | +150 | $^\circ\text{C}$ | |
| PACKAGE THERMAL RESISTANCE | | | | | | |
| 3-lead SOT-89 | θ_{JA} | — | 73 | — | $^\circ\text{C/W}$ | |
| | θ_{JC} | — | 15 | — | $^\circ\text{C/W}$ | |

THERMAL CHARACTERISTICS

| Package | I_D (Note 1) (Continuous) (mA) | I_D (Pulsed) (A) | Power Dissipation at $T_A = 25^\circ\text{C}$ (Note 2) (W) | I_{DR} (Note 1) (mA) | I_{DRM} (A) |
|---------------|---|--------------------------|--|------------------------------------|------------------|
| 3-lead SOT-89 | 365 | 1.8 | 1.6 | 365 | 1.8 |

Note 1: I_D (continuous) is limited by maximum rated T_J .

2: $T_A = 25^\circ\text{C}$. Mounted on an FR5 Board, 25 mm x 25 mm x 1.57 mm. Significant P_D increase is possible on ceramic substrate.

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g. outside specified power supply range) and therefore outside the warranted range.

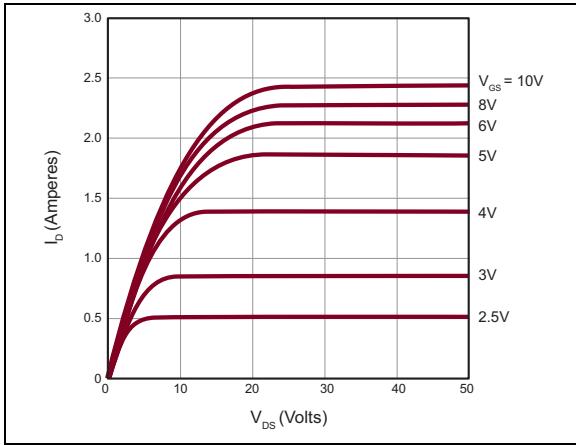


FIGURE 2-1: Output Characteristics.

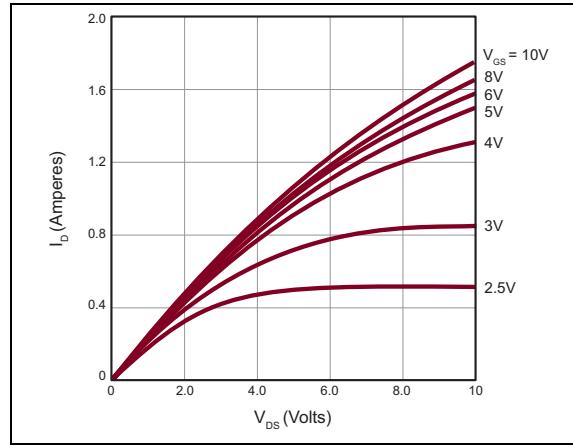


FIGURE 2-4: Saturation Characteristics.

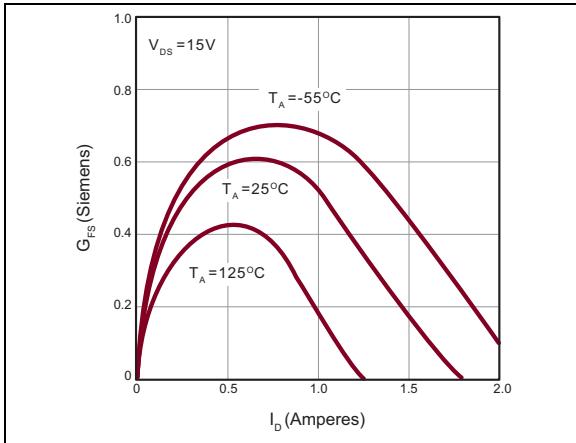


FIGURE 2-2: Transconductance vs. Drain Current.

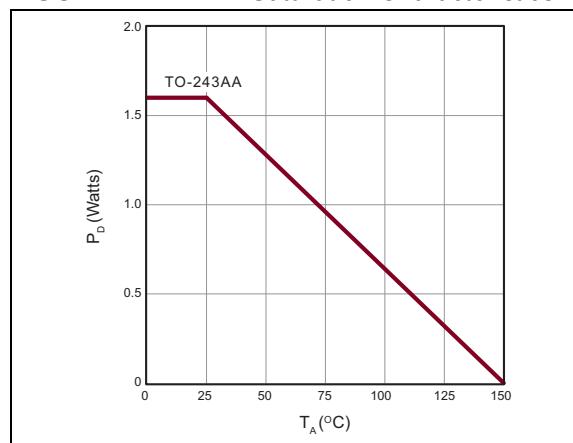


FIGURE 2-5: Power Dissipation vs. Ambient Temperature.

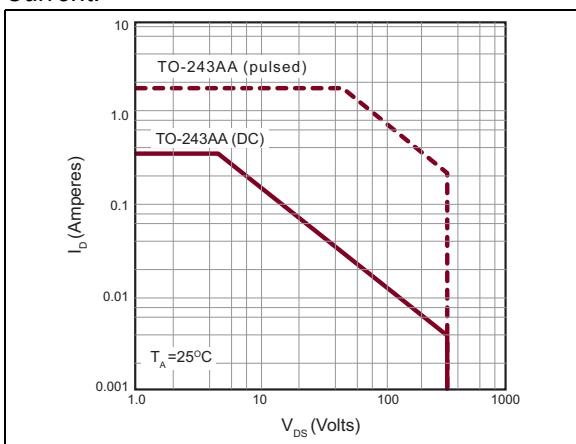


FIGURE 2-3: Maximum Rated Safe Operating Area.

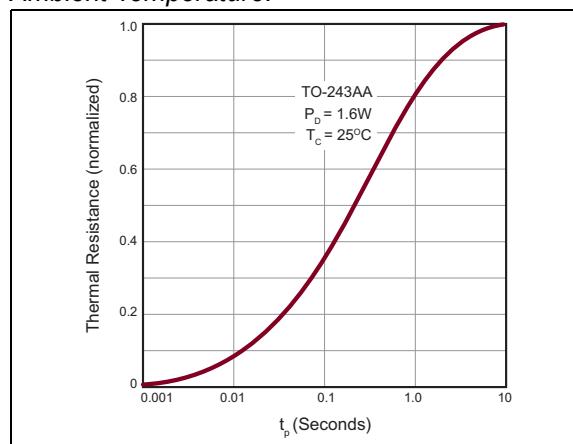


FIGURE 2-6: Thermal Response Characteristics.

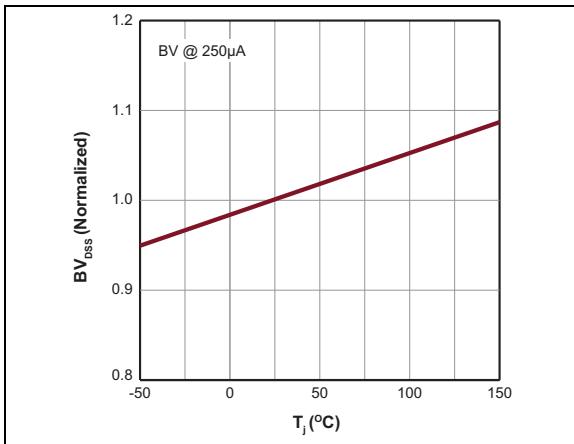


FIGURE 2-7: BV_{DSS} Variation with Temperature.

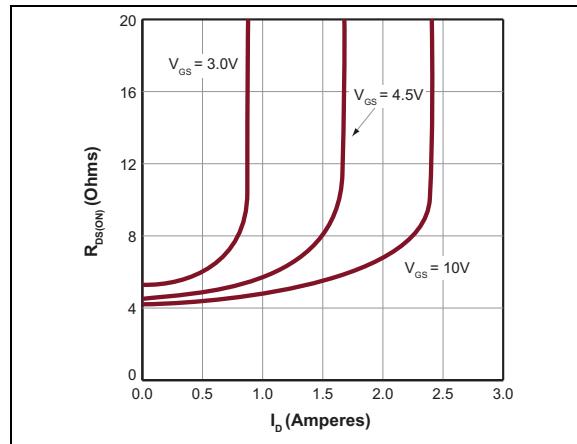


FIGURE 2-10: On-Resistance vs. Drain Current.

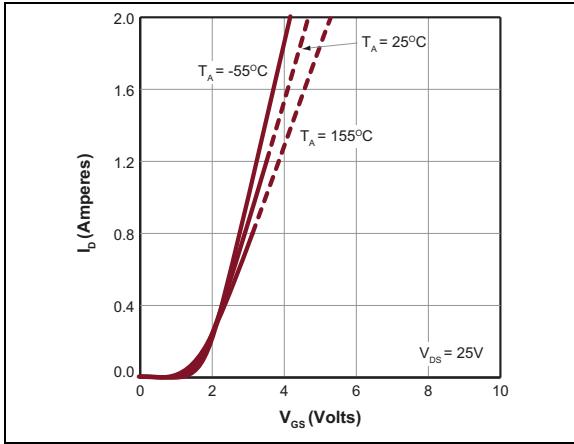


FIGURE 2-8: Transfer Characteristics.

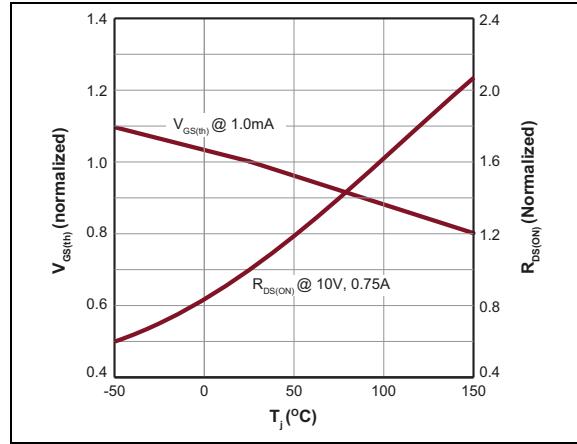


FIGURE 2-11: $V_{GS(th)}$ and $R_{DS(ON)}$ with Temperature.

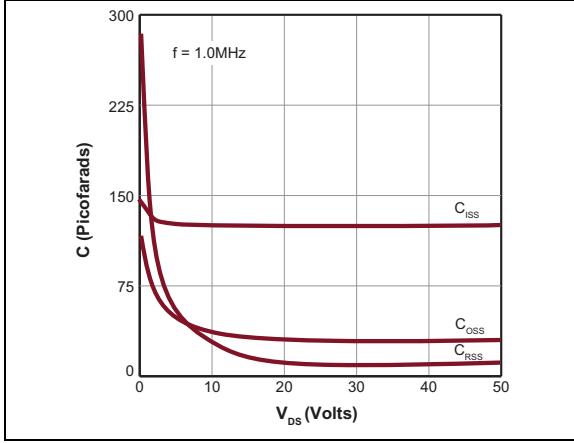


FIGURE 2-9: Capacitance vs. Drain-to-Source Voltage.

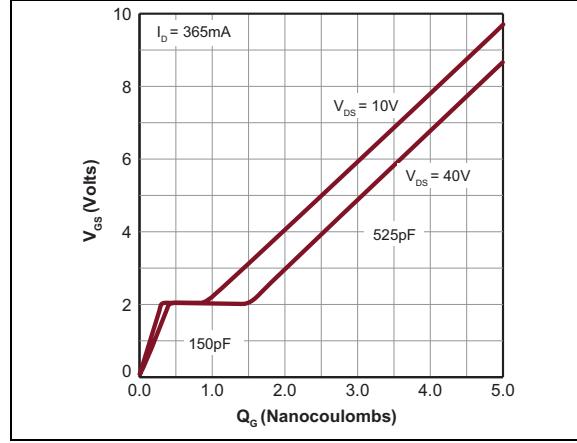


FIGURE 2-12: Gate Drive Dynamic Characteristics.

3.0 PIN DESCRIPTION

Table 3-1 shows details on the pins of TN2435. Refer to **Package Type** for the location of the pins.

TABLE 3-1: PIN FUNCTION TABLE

| Pin Number | Pin Name | Description |
|------------|----------|-------------|
| 1 | Gate | Gate |
| 2,4 | Drain | Drain |
| 3 | Source | Source |

4.0 FUNCTIONAL DESCRIPTION

Figure 4-1 illustrates the switching waveforms and test circuit for TN2435.

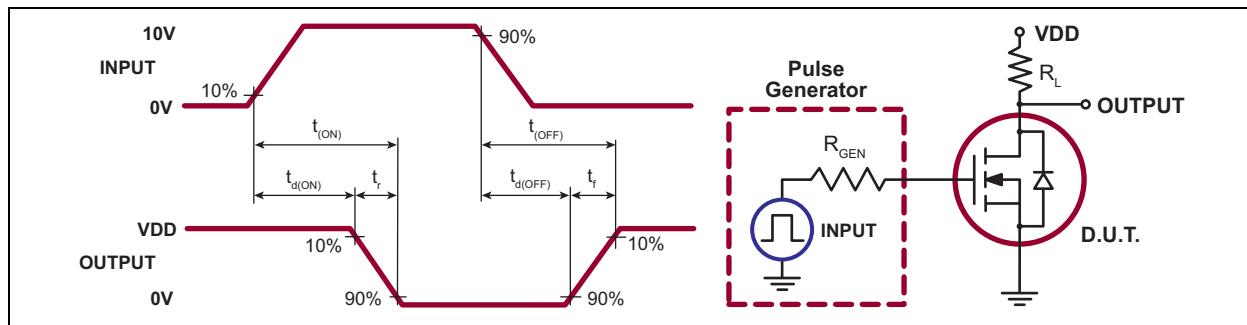


FIGURE 4-1: Switching Waveforms and Test Circuit.

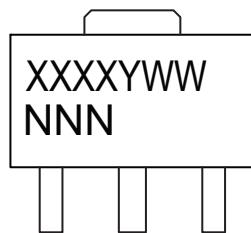
TABLE 4-1: PRODUCT SUMMARY

| BV_{DSS}/BV_{DGS} (V) | $R_{DS(ON)}$ (Maximum) (Ω) | I_{DSS} (Minimum) (A) |
|----------------------------|---|-------------------------------|
| 350 | 6 | 1 |

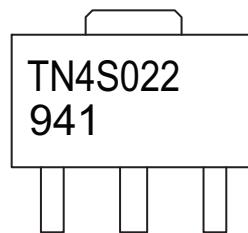
5.0 PACKAGING INFORMATION

5.1 Package Marking Information

3-lead SOT-89



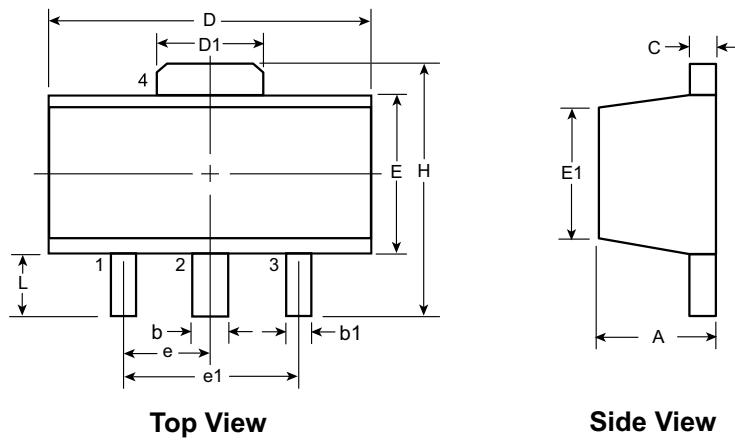
Example



| | | |
|----------------|--------|--|
| Legend: | XX...X | Product Code or Customer-specific information |
| | Y | Year code (last digit of calendar year) |
| | YY | Year code (last 2 digits of calendar year) |
| | WW | Week code (week of January 1 is week '01') |
| | NNN | Alphanumeric traceability code |
| | (e3) | Pb-free JEDEC® designator for Matte Tin (Sn) |
| * | | This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package. |

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for product code or customer-specific information. Package may or not include the corporate logo.

3-Lead TO-243AA (SOT-89) Package Outline (N8)



Note: For the most current package drawings, see the Microchip Packaging Specification at www.microchip.com/packaging.

| Symbol | A | b | b1 | C | D | D1 | E | E1 | e | e1 | H | L | |
|--------------------|-----|------|------|------|------|------|------|------|-------------------|-------------|-------------|------|-------------------|
| Dimensions (mm) | MIN | 1.40 | 0.44 | 0.36 | 0.35 | 4.40 | 1.62 | 2.29 | 2.00 ^t | 1.50 BSC | 3.00 BSC | 3.94 | 0.73 ^t |
| | NOM | - | - | - | - | - | - | - | - | | | - | - |
| | MAX | 1.60 | 0.56 | 0.48 | 0.44 | 4.60 | 1.83 | 2.60 | 2.29 | | | 4.25 | 1.20 |

JEDEC Registration TO-243, Variation AA, Issue C, July 1986.

^t This dimension differs from the JEDEC drawing.

Drawings not to scale.

TN2435

NOTES:

APPENDIX A: REVISION HISTORY

Revision A (November 2020)

- Converted Supertex Doc# DSFP-TN2435 to Microchip DS20005946A
- Changed the package marking format
- Made minor text changes throughout the document

TN2435

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

| PART NO. | XX | - | X | - | X | Example: |
|----------------|-----------------|---|---|------------|---|--|
| Device | Package Options | | Environmental | Media Type | | |
| Device: | TN2435 | = | N-Channel Enhancement-Mode Vertical DMOS FET | | | a) TN2435N8-G: N-Channel Enhancement-Mode, Vertical DMOS FET, 3-lead SOT-89, 2000/Reel |
| Package: | N8 | = | 3-lead SOT-89 | | | |
| Environmental: | G | = | Lead (Pb)-free/RoHS-compliant Package | | | |
| Media Type: | (blank) | = | 2000/Reel for an N8 Package | | | |

Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specifications contained in their particular Microchip Data Sheet.
 - Microchip believes that its family of products is secure when used in the intended manner and under normal conditions.
 - There are dishonest and possibly illegal methods being used in attempts to breach the code protection features of the Microchip devices. We believe that these methods require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Attempts to breach these code protection features, most likely, cannot be accomplished without violating Microchip's intellectual property rights.
 - Microchip is willing to work with any customer who is concerned about the integrity of its code.
 - Neither Microchip nor any other semiconductor manufacturer can guarantee the security of its code. Code protection does not mean that we are guaranteeing the product is "unbreakable." Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.
-

Information contained in this publication is provided for the sole purpose of designing with and using Microchip products. Information regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications.

THIS INFORMATION IS PROVIDED BY MICROCHIP "AS IS". MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION INCLUDING BUT NOT LIMITED TO ANY IMPLIED WARRANTIES OF NON-INFRINGEMENT, MERCHANTABILITY, AND FITNESS FOR A PARTICULAR PURPOSE OR WARRANTIES RELATED TO ITS CONDITION, QUALITY, OR PERFORMANCE.

IN NO EVENT WILL MICROCHIP BE LIABLE FOR ANY INDIRECT, SPECIAL, PUNITIVE, INCIDENTAL OR CONSEQUENTIAL LOSS, DAMAGE, COST OR EXPENSE OF ANY KIND WHATSOEVER RELATED TO THE INFORMATION OR ITS USE, HOWEVER CAUSED, EVEN IF MICROCHIP HAS BEEN ADVISED OF THE POSSIBILITY OR THE DAMAGES ARE FORESEEABLE. TO THE FULLEST EXTENT ALLOWED BY LAW, MICROCHIP'S TOTAL LIABILITY ON ALL CLAIMS IN ANY WAY RELATED TO THE INFORMATION OR ITS USE WILL NOT EXCEED THE AMOUNT OF FEES, IF ANY, THAT YOU HAVE PAID DIRECTLY TO MICROCHIP FOR THE INFORMATION. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights unless otherwise stated.

Trademarks

The Microchip name and logo, the Microchip logo, Adaptec, AnyRate, AVR, AVR logo, AVR Freaks, BesTime, BitCloud, chipKIT, chipKIT logo, CryptoMemory, CryptoRF, dsPIC, FlashFlex, flexPWR, HELDO, IGLOO, JukeBlox, KeeLoq, Kleer, LANCheck, LinkMD, maxStylus, maXTouch, MediaLB, megaAVR, Microsemi, Microsemi logo, MOST, MOST logo, MPLAB, OptoLyzer, PackeTime, PIC, picoPower, PICSTART, PIC32 logo, PolarFire, Prochip Designer, QTouch, SAM-BA, SenGenuity, SpyNIC, SST, SST Logo, SuperFlash, Symmetricom, SyncServer, Tachyon, TimeSource, tinyAVR, UNI/O, Vectron, and XMEGA are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

AgileSwitch, APT, ClockWorks, The Embedded Control Solutions Company, EtherSynch, FlashTec, Hyper Speed Control, HyperLight Load, IntelliMOS, Libero, motorBench, mTouch, Powermite 3, Precision Edge, ProASIC, ProASIC Plus, ProASIC Plus logo, Quiet-Wire, SmartFusion, SyncWorld, Temux, TimeCesium, TimeHub, TimePictra, TimeProvider, WinPath, and ZL are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Adjacent Key Suppression, AKS, Analog-for-the-Digital Age, Any Capacitor, AnyIn, AnyOut, Augmented Switching, BlueSky, BodyCom, CodeGuard, CryptoAuthentication, CryptoAutomotive, CryptoCompanion, CryptoController, dsPICDEM, dsPICDEM.net, Dynamic Average Matching, DAM, ECAN, Espresso T1S, EtherGREEN, IdealBridge, In-Circuit Serial Programming, ICSP, INICnet, Intelligent Paralleling, Inter-Chip Connectivity, JitterBlocker, maxCrypto, maxView, memBrain, Mindi, MiWi, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, MultiTRAK, NetDetach, Omniscient Code Generation, PICDEM, PICDEM.net, PICkit, PICtail, PowerSmart, PureSilicon, QMatrix, REAL ICE, Ripple Blocker, RTAX, RTG4, SAM-ICE, Serial Quad I/O, simpleMAP, SimpliPHY, SmartBuffer, SMART-I.S., storClad, SQL, SuperSwitcher, SuperSwitcher II, Switchtec, SynchroPHY, Total Endurance, TSHARC, USBCheck, VariSense, VectorBlox, VeriPHY, ViewSpan, WiperLock, XpressConnect, and ZENA are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

The Adaptec logo, Frequency on Demand, Silicon Storage Technology, and Symmcom are registered trademarks of Microchip Technology Inc. in other countries.

GestIC is a registered trademark of Microchip Technology Germany II GmbH & Co. KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 2020, Microchip Technology Incorporated, All Rights Reserved.

ISBN: 978-1-5224-7202-5

For information regarding Microchip's Quality Management Systems, please visit www.microchip.com/quality.



MICROCHIP

Worldwide Sales and Service

AMERICAS

Corporate Office
2355 West Chandler Blvd.
Chandler, AZ 85224-6199
Tel: 480-792-7200
Fax: 480-792-7277
Technical Support:
<http://www.microchip.com/support>
Web Address:
www.microchip.com

Atlanta

Duluth, GA
Tel: 678-957-9614
Fax: 678-957-1455

Austin, TX

Tel: 512-257-3370

Boston

Westborough, MA
Tel: 774-760-0087
Fax: 774-760-0088

Chicago

Itasca, IL
Tel: 630-285-0071
Fax: 630-285-0075

Dallas

Addison, TX
Tel: 972-818-7423
Fax: 972-818-2924

Detroit

Novi, MI
Tel: 248-848-4000

Houston, TX

Tel: 281-894-5983

Indianapolis

Noblesville, IN
Tel: 317-773-8323
Fax: 317-773-5453
Tel: 317-536-2380

Los Angeles

Mission Viejo, CA
Tel: 949-462-9523
Fax: 949-462-9608
Tel: 951-273-7800

Raleigh, NC

Tel: 919-844-7510

New York, NY

Tel: 631-435-6000

San Jose, CA

Tel: 408-735-9110
Tel: 408-436-4270

Canada - Toronto

Tel: 905-695-1980
Fax: 905-695-2078

ASIA/PACIFIC

Australia - Sydney
Tel: 61-2-9868-6733
China - Beijing
Tel: 86-10-8569-7000
China - Chengdu
Tel: 86-28-8665-5511
China - Chongqing
Tel: 86-23-8980-9588
China - Dongguan
Tel: 86-769-8702-9880
China - Guangzhou
Tel: 86-20-8755-8029
China - Hangzhou
Tel: 86-571-8792-8115
China - Hong Kong SAR
Tel: 852-2943-5100
China - Nanjing
Tel: 86-25-8473-2460
China - Qingdao
Tel: 86-532-8502-7355
China - Shanghai
Tel: 86-21-3326-8000
China - Shenyang
Tel: 86-24-2334-2829
China - Shenzhen
Tel: 86-755-8864-2200
China - Suzhou
Tel: 86-186-6233-1526
China - Wuhan
Tel: 86-27-5980-5300
China - Xian
Tel: 86-29-8833-7252
China - Xiamen
Tel: 86-592-2388138
China - Zhuhai
Tel: 86-756-3210040

ASIA/PACIFIC

India - Bangalore
Tel: 91-80-3090-4444
India - New Delhi
Tel: 91-11-4160-8631
India - Pune
Tel: 91-20-4121-0141
Japan - Osaka
Tel: 81-6-6152-7160
Japan - Tokyo
Tel: 81-3-6880- 3770
Korea - Daegu
Tel: 82-53-744-4301
Korea - Seoul
Tel: 82-2-554-7200
Malaysia - Kuala Lumpur
Tel: 60-3-7651-7906
Malaysia - Penang
Tel: 60-4-227-8870
Philippines - Manila
Tel: 63-2-634-9065
Singapore
Tel: 65-6334-8870
Taiwan - Hsin Chu
Tel: 886-3-577-8366
Taiwan - Kaohsiung
Tel: 886-7-213-7830
Taiwan - Taipei
Tel: 886-2-2508-8600
Thailand - Bangkok
Tel: 66-2-694-1351
Vietnam - Ho Chi Minh
Tel: 84-28-5448-2100

EUROPE

Austria - Wels
Tel: 43-7242-2244-39
Fax: 43-7242-2244-393
Denmark - Copenhagen
Tel: 45-4485-5910
Fax: 45-4485-2829
Finland - Espoo
Tel: 358-9-4520-820
France - Paris
Tel: 33-1-69-53-63-20
Fax: 33-1-69-30-90-79
Germany - Garching
Tel: 49-8931-9700
Germany - Haan
Tel: 49-2129-3766400
Germany - Heilbronn
Tel: 49-7131-72400
Germany - Karlsruhe
Tel: 49-721-625370
Germany - Munich
Tel: 49-89-627-144-0
Fax: 49-89-627-144-44
Germany - Rosenheim
Tel: 49-8031-354-560
Israel - Ra'anana
Tel: 972-9-744-7705
Italy - Milan
Tel: 39-0331-742611
Fax: 39-0331-466781
Italy - Padova
Tel: 39-049-7625286
Netherlands - Drunen
Tel: 31-416-690399
Fax: 31-416-690340
Norway - Trondheim
Tel: 47-7288-4388
Poland - Warsaw
Tel: 48-22-3325737
Romania - Bucharest
Tel: 40-21-407-87-50
Spain - Madrid
Tel: 34-91-708-08-90
Fax: 34-91-708-08-91
Sweden - Gothenberg
Tel: 46-31-704-60-40
Sweden - Stockholm
Tel: 46-8-5090-4654
UK - Wokingham
Tel: 44-118-921-5800
Fax: 44-118-921-5820